### **TELEFUNKEN Semiconductors**

# DH Backlighting LED, ø 3 mm Tinted Non-Diffused Package

Color	Туре	Technology	Angle of Half Intensity
			±φ
Double hetero red	TLVD4200	GaAlAs on GaAs	85°

# **Description**

The TLVD4200 serie was developed for backlighting in the extrem bright double heterojunction (DH) red GaAlAs on GaAs technology. Due to its special shape the spatial distribution of the radiation is qualified for backlighting.

To optimize the brightness of backlighting a custom—built reflector (with scattering) is required. Uniform illumination can be enhanced by covering the front of the reflector with diffusor material.

This is a bright and flexible solution for backlighting different areas.

# 96 11665

### **Features**

- High brightness
- Wide viewing angle
- Categorized for luminous flux
- Available in DH red
- Tinted clear package
- Low power dissipation
- Low self heating
- Rugged design
- High reliability

# **Applications**

Backlighting of display panels, LCD displays, symbols on switches, keyboards, graphic boards and measuring scales Illumination of large areas e.g. dot matrix displays

Rev. A1: 01.06.1995

**TELEFUNKEN Semiconductors** 

# **Absolute Maximum Ratings**

 $T_{amb} = 25$ °C, unless otherwise specified

### Double hetero red (TLVD4200)

Parameter	Test Conditions	Туре	Symbol	Value	Unit
Reverse voltage			$V_{R}$	6	V
DC forward current			$I_{\mathrm{F}}$	50	mA
Surge forward current	$t_p \leq 10 \mu s$		$I_{FSM}$	1	A
Power dissipation	$T_{amb} \le 60^{\circ}C$		$P_{V}$	100	mW
Junction temperature			T <sub>i</sub>	100	°C
Operating temperature range			T <sub>amb</sub>	-20 to +100	°C
Storage temperature range			$T_{stg}$	-55 to +100	°C
Soldering temperature	$t \leq 5 s$ ,		T <sub>sd</sub>	260	°C
	2 mm from body				
Thermal resistance junction/ambient			$R_{thJA}$	400	K/W

# **Optical and Electrical Characteristics**

 $T_{amb} = 25$ °C, unless otherwise specified

### Double hetero red (TLVD4200)

Parameter	Test Conditions	Type	Symbol	Min	Тур	Max	Unit
Luminous flux	$I_F = 15 \text{ mA}$		$\phi_{ m V}$	40	80		mlm
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_{ m d}$		640		nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_{\mathrm{p}}$		650		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		φ		±85		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_{\mathrm{F}}$		1.8	2.2	V
Reverse voltage	$I_R = 10 \mu A$		$V_{R}$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1$ MHz		Cj		50		pF

2 (6) Rev. A1: 01.06.1995

# **Typical Characteristics** $(T_{amb} = 25^{\circ}C, unless otherwise specified)$

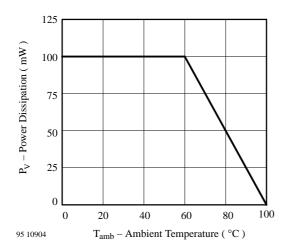


Figure 1. Power Dissipation vs. Ambient Temperature

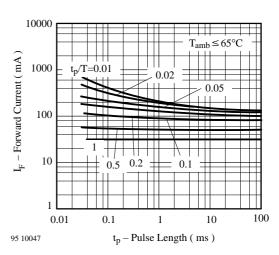


Figure 3. Forward Current vs. Pulse Length

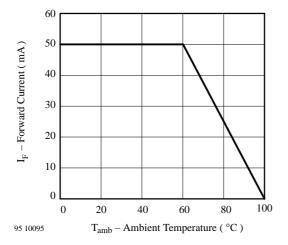


Figure 2. Forward Current vs. Ambient Temperature

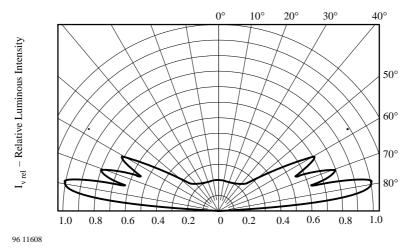


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

Rev. A1: 01.06.1995

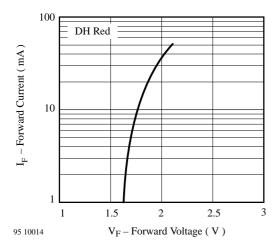


Figure 5. Forward Current vs. Forward Voltage

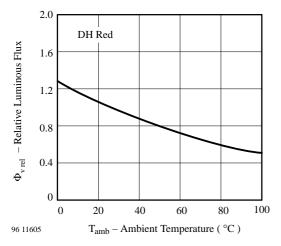


Figure 6. Rel. Luminous Flux vs. Ambient Temperature

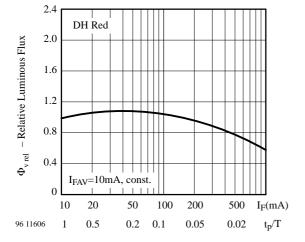


Figure 7. Rel. Luminous Flux vs. Forw. Current/Duty Cycle

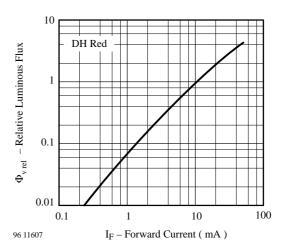


Figure 8. Relative Luminous Flux vs. Forward Current

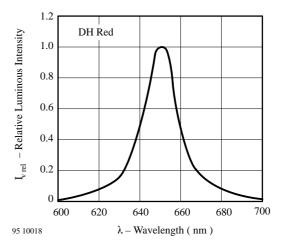
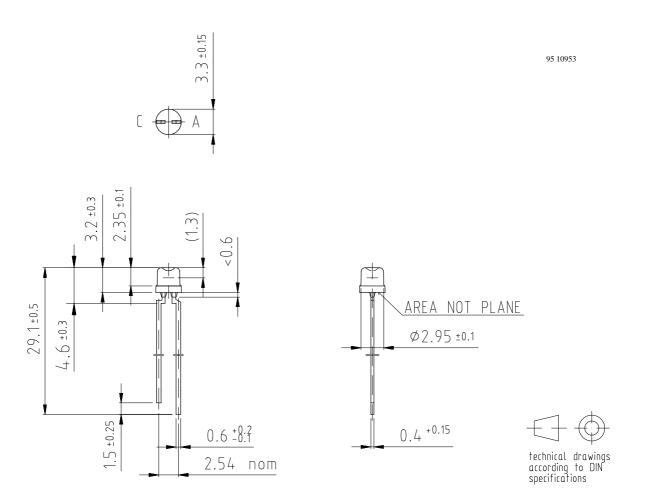


Figure 9. Relative Luminous Intensity vs. Wavelength

4 (6) Rev. A1: 01.06.1995

# **TEMIC**

# **Dimensions in mm**



Rev. A1: 01.06.1995

EMIC

# **TLVD420.**

# **Ozone Depleting Substances Policy Statement**

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

6 (6) Rev. A1: 01.06.1995